TO-220AB-L



150V N-Channel MOSFET

Voltage	150 V	Rdson	7.5 mΩ
Current	125 A	Qg	97 nC

Feature:

• $R_{DS(ON) Max}$, $V_{GS}@10V$: 7.5m Ω

• $R_{DS(ON) Max}$, $V_{GS}@7V$: $9m \Omega$

High Speed Switching and Low RDS(ON)

• 100% Avalanche Tested

• 100% Rg Tested

• Lead free in compliance with EU RoHS 2.0

• BMS, BLDC. SMPS SR.

Green molding compound as per IEC 61249 standard Mechanical Data Case: TO-220AB-L package Terminals: Solderable per MIL-STD-750, Method 2026 Approx. Weight: 0.0739 ounces, 2.0948 grams Application Drain Gate Source Source Source

Absolute Maximum Ratings (T_A = 25 °C unless otherwise specified)

SYMBOL LIMIT **UNITS PARAMETER** Drain-Source Voltage V_{DS} 150 V Gate-Source Voltage ±20 V_{GS} T_C=25°C 125 Continuous Drain Current(Note 3) Α I_D Tc=100°C 88.5 Pulsed Drain Current Tc=25°C 350 I_{DM} Α Single Pulse Avalanche Current (Note 5) Α I_{AS} 36 Single Pulse Avalanche Energy (Note 5) 655 mJ E_{AS} Tc=25°C 258.6 Power Dissipation Pn W T_C=100°C 129 Operating Junction and Storage Temperature Range ٥С T_{J}, T_{STG} -55~175

Thermal Characteristics

PARAM	ETER	SYMBOL	MAXIMUM	UNITS
	Junction-to-Case	$R_{ heta JC}$	0.58	°C/W
Thermal Resistance	Junction-to-Ambient (Note 3)	$R_{ hetaJA}$	62.5	°C/W





Electrical Characteristics (T_A = 25 °C unless otherwise specified)

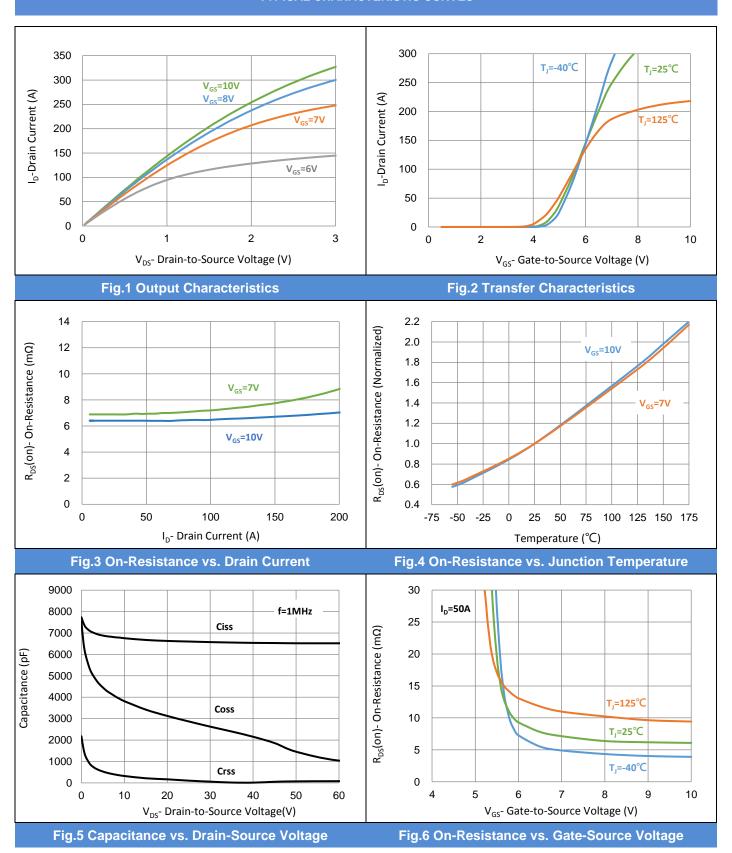
PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS	
Static							
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =250uA	150	-	V		
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =250uA	2	3.2			
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =10V, I _D =50A	-	6.3	7.5		
(Note 1)	R _{DS(on)}	V _{GS} =7V, I _D =25A		6.8	9	mΩ	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =120V, V _{GS} =0V	-	-	1	uA	
Gate-Source Leakage Current	I _{GSS}	V_{GS} =±20V, V_{DS} =0V	-	-	±100	nA	
Dynamic (Note 6)							
Total Gate Charge	0	V _{DS} =75V, I _D =50A,	-	72	-	nC	
	Qg	V _{GS} =7V					
	Qg	Qg	-	97	-		
Gate-Source Charge	Qgs	V _{DS} =75V, I _D =50A, V _{GS} =10V	-	31	-		
Gate-Drain Charge	Qgd	VGS=10V	-	23	-		
Input Capacitance	Ciss	751/ 1/ 01/	-	6511	-	pF	
Output Capacitance	Coss	V _{DS} =75V, V _{GS} =0V,	-	862	-		
Reverse Transfer Capacitance	Crss	F=1MHz	-	83	-		
Turn-On Delay Time	td(on)	\/ 75\/ 50A	-	53	-		
Turn-On Rise Time	tr	V _{DD} =75V, I _D =50A,	-	111	-		
Turn-Off Delay Time	td(off)	$V_{GS}=10V, R_{G}=2\Omega$ (Note 2)	-	99	-	ns	
Turn-Off Fall Time	t _f	(14010 2)	-	113	-		
Gate Resistance	Rg	f=1.0MHz	-	2.7	-	Ω	
Drain-Source Diode							
Diode Forward Voltage	V _{SD}	I _S =50A, V _{GS} =0V	-	0.9	1.3	V	
Reverse Recovery Charge	Qrr	Is=50A	-	541	-	nC	
Reverse Recovery Time	T _{rr}	di/dt=100A/µs	-	117	-	ns	

NOTES:

- 1. Pulse width<300us, Duty cycle<2%
- 2. Essentially independent of operating temperature typical characteristics.
- 3. The maximum current rating is silicon limited.
- 4. R0JA is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch2 with 2oz.square pad of copper.
- 5. The test condition is L=1mH, IAS=36.2A, VDD=50V, VGS=10V, RG=25ohm, Starting T_J=25℃
- 6. Guaranteed by design, not subject to production testing.

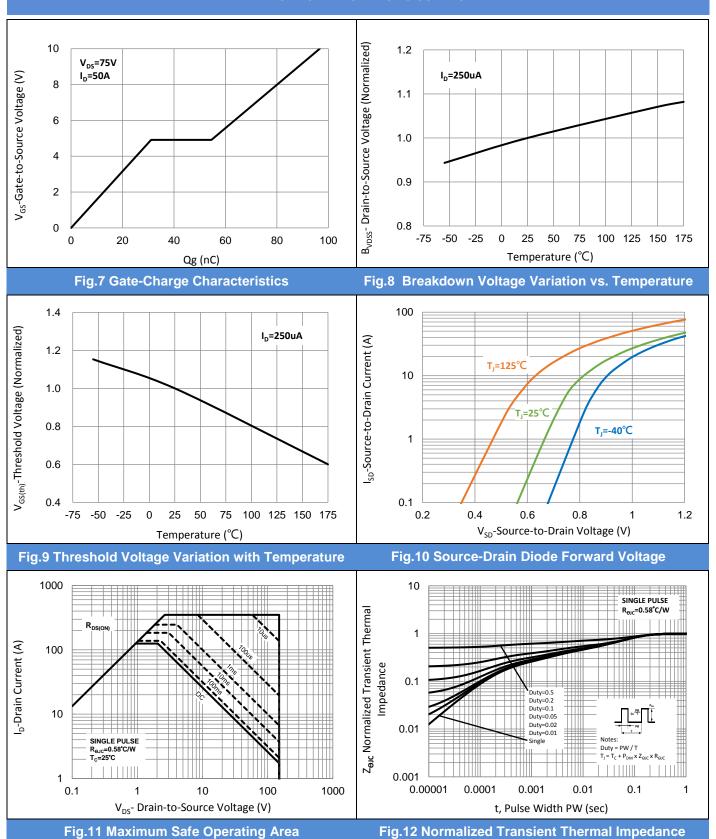


TYPICAL CHARACTERISTIC CURVES



PSMP075N15NS1

TYPICAL CHARACTERISTIC CURVES







TYPICAL CHARACTERISTIC CURVES

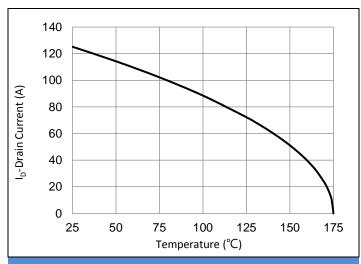


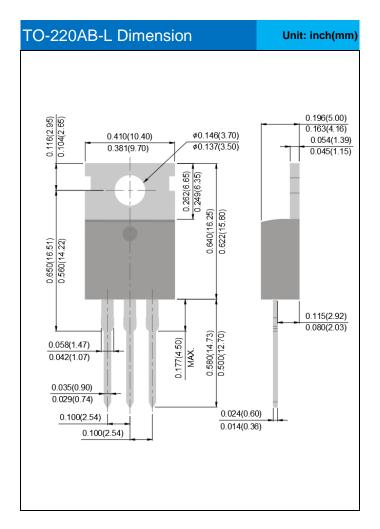
Fig.13 Drain Current vs. Case Temperature



Product and Packing Information

Part No.	Package Type	Packing Type	Marking
PSMP075N15NS1	TO-220AB-L	50pcs / Tube	075N15NS

Packaging Information



Marking Diagram

PJ 075N15NS YWLL x Y = Year Code

W = Week Code (A~Z)

LL = Lot Code $(00\sim99)$

x = Production Line Code





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